

Features:

- High-Side Current Sense Amplifier
- 2.7V to 60V Input Range
- 0.7% Typical Full Scale Accuracy
- Scalable Output Voltage
- SOIC Package

Applications:

- Power Management Systems
- Smart Battery Packs
- Battery Chargers
- Battery Powered Portable Equipment
- DC Motor Control

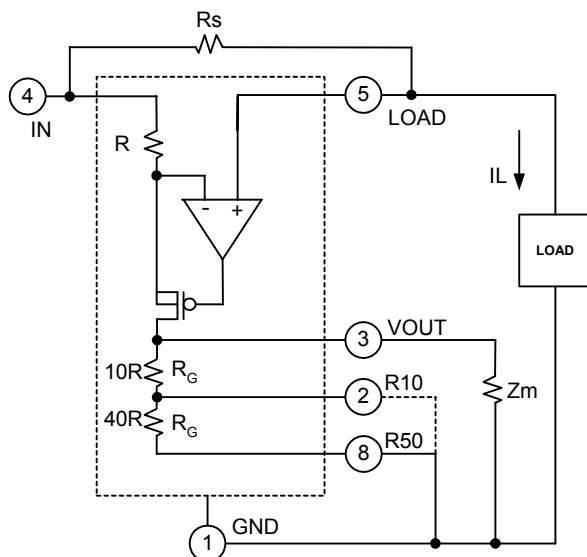
General Description

The IXI848A is a precision high side current sense monitor. High side power-line monitoring offers the advantage of allowing the ground plane to remain undisturbed when sensing load currents.

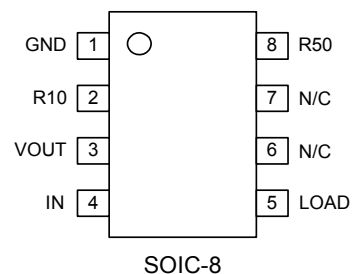
An external sense resistor sets the range of the amplified ground-referenced output monitoring voltage. The output voltage is amplified by a selectable fixed gain of either 10 or 50. With an input voltage range up to 60V, and output gain of up to 50, the IXI848A is designed to address a wide variety of current sense applications.

The IXI848A operates over a temperature range of -40°C to +85°C. The IXI848A is available in an 8-Lead SOIC package.

IXI848A Functional Block Diagram and General Application Circuit



IXI848A SOIC PIN Configuration



Ordering Information

Part No.	Description	Package	Quantity
IXI848AS1	High Side Current	SOIC-8	98 (Tube)
XI848AS1T/R	Sense Monitor	SOIC-8	2500 (T&R)

Absolute Maximum Ratings

Parameter	Rating
Voltage to IN (pin 4)	-0.3V to +65V
Differential Input Voltage (V_{SENSE})	$\pm 0.4V$
Input Current to any pin	$\pm 10mA$
Operating Ambient Temp Range	-40°C to +85°C
Operating Junction Temp Range	-40°C to +125°C
θ_{JA}	150°C/W
θ_{JC}	40°C/W
Storage Temp Range	-65°C to +150°C
Lead Temperature (Soldering, 10 sec)	+300°C

Absolute Maximum Ratings are stress ratings. Stresses in excess of these ratings can cause permanent damage to the device. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this data sheet is not implied. Exposure of the device to the absolute maximum ratings for an extended period may degrade the device and affect its reliability.

ESD Warning

ESD (electrostatic discharge) sensitive device. Although the IXI848A feature proprietary ESD protection circuitry, permanent damage may be sustained if subjected to high energy electrostatic discharges. Proper ESD precautions are recommended to avoid performance degradation or loss of functionality.

Electrical Characteristics

$T_A = 25^\circ C$, $V_{IN} = 2.7V$ to $40V$, unless otherwise noted

Parameter	Symbol	Conditions		Min	Typ	Max	Unit
Operating Voltage Range	V _{IN}			2.7		60	V
Supply Current	I _{IN}	V _{IN} = 20V, V _{SENSE} = 0V, I _{LOAD} = 0A			.065	.130	mA
Full Scale Sense Voltage	V _{SENSE}				150		mV
Input Offset Voltage	V _{OS}	V _{IN} = 12V		-2.0	±0.5	2.0	mV
Full Scale Accuracy		V _{SENSE} = 100mV, V _{IN} = 12V T _A = +25°C			±0.7		%
Total OUT Voltage Error (Note 1, Note 2)		V _{SENSE} = 100mV V _{IN} = 12V	T _A = +25°C		±0.7		%
			Δ @ T _A = -40° to +85°C		±0.3		
		V _{SENSE} = 100mV V _{IN} = 40V	T _A = +25°C		±0.8		%
			Δ @ T _A = -40° to +85°C		±0.4		
Gain Accuracy (Note 2)		V _{SENSE} = 20mV to 100mV V _{IN} = 12V, 40V	T _A = +25°C		±0.5		%
			Δ @ T _A = -40° to +85°C		±0.1		
Gain Setting Resistance	R _G	V _{IN} = 12V	Gain = 10V/V	23	33	43	kΩ
		V _{SENSE} = 100mV	Gain = 50V/V	115	165	215	kΩ

Note 1: Total OUT voltage error is the sum of gain and offset voltage errors.

Note 2: Production Tested at $T_A = 25^\circ C$.

Pin Description and Configuration

SOIC	Name	Description
1	GND	Ground
2	R10	Connecting R10 to GND, (R50=N/C) selects a VOUT voltage that is 10X the voltage across R _{SENSE} .
3	VOUT	Output voltage proportional to the voltage across R _{SENSE} .
4	IN	Positive supply terminal and power connection for the external Sense Resistor.
5	LOAD	Load-side connection to the external Sense Resistor.
6	N/C	No Connect
7	N/C	No Connect
8	R50	Connecting R50 to GND, (R10=N/C) selects a VOUT voltage that is 50X the voltage across R _{SENSE} .

Detailed Circuit Description

The IXI848A is a precision high side current sense monitor featuring an input voltage range of 2.7V to 60V, and a selectable ground referenced fixed gain output of either 10 or 50.

A small voltage developed across an external sense resistor (R_S), is converted to an amplified ground referenced voltage output at VOUT, (Figure 1). The amplifier's non-inverting input is high impedance making the voltage at that terminal equal to $V_{IN} - (I_L)(R_S)$. The amplifier forces the high impedance inverting terminal to equal the non-inverting input voltage by turning on the P-Channel MOS FET.

As the P-Channel MOS FET is biased on by the amplifier output, current is sourced through R_G (10R or 10R+40R), to produce a voltage equal to $V_{IN} - (I_L)(R_S)$ at the inverting input of the amplifier. This develops a voltage across the inverting input resistor, R that matches the sense voltage across R_S , plus any associated input offset voltage, (V_{IO}). Consequently, the voltage at VOUT corresponds to R_G / R .

Output: $VOUT = G [(I_L)(R_S) + V_{IO}]$

Gain: $G = (R_G)(Z_M) / R (R_G (R_G + Z_M))$

$R_G = 10R$ or $50R$ selectable

Temperature coefficient:

(all on-chip resistors) $R = 700\text{ppm} / ^\circ\text{C}$ typical

R_{SENSE} Component Selection

The R_{SENSE} value should be selected such that the voltage across R_{SENSE} is at full-scale for the load current to be monitored. Operating the IXI848A at or near the full-scale sense voltage will minimize

the error component associated with the input offset voltage of the internal op amp.

The IXI848A can be configured to measure a wide selection of currents by using different R_{SENSE} values. Some common values for typical operation of the IXI848A are listed in the following table.

Full-Scale I_L (A)	R_{SENSE} R_S (Ω)	Gain (V/V)	VOUT (V) $V_{SENSE} = 150\text{mV}$
0.15	1.0	10	1.5
1.5	0.1	10	1.5
5	0.01	50	2.5
100	0.001	50	5

Output Impedance

The VOUT output is a current source driving a $33\text{k}\Omega$ resistance to ground for a gain of 10, or a $165\text{k}\Omega$ resistance to ground for a gain of 50. Output gain is reduced by resistive loading of the VOUT terminal. The impedance of the external monitor load (Z_M) should be chosen high enough to maintain the desired accuracy. Buffering of the VOUT terminal with a high-impedance input stage may be required to minimize output errors.

The following formulas quantify the percent error introduced by output loading:

For a Gain of 10

$$\%_{\text{ERROR}} = 100 [R_{\text{LOAD}} / (33\text{k}\Omega + R_{\text{LOAD}}) - 1]$$

For a Gain of 50

$$\%_{\text{ERROR}} = 100 [R_{\text{LOAD}} / (165\text{k}\Omega + R_{\text{LOAD}}) - 1]$$

$R_{\text{LOAD}} =$ the external load applied to VOUT

Typical Performance Characteristics

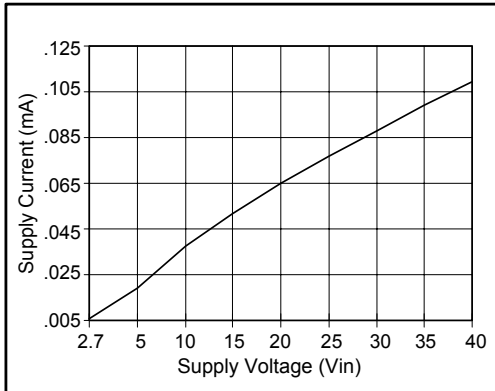


Fig 3. Supply Current vs. Voltage

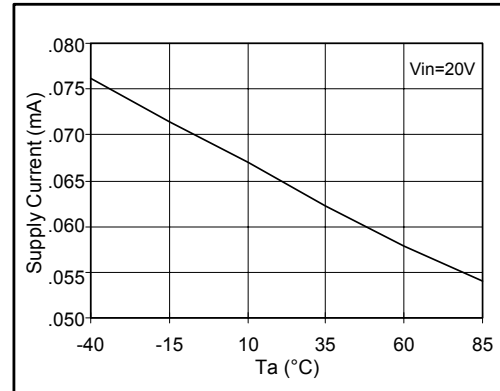


Fig 4. Supply Current vs. Temperature

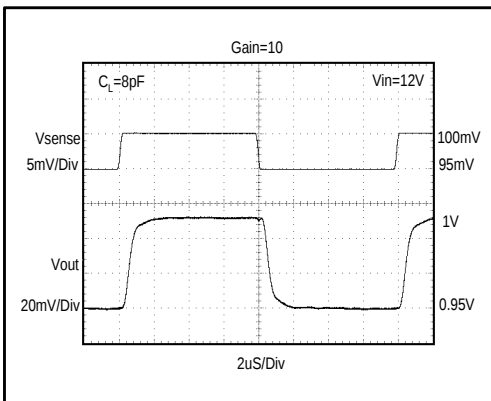


Fig 5. Small Signal Transient Response 10X

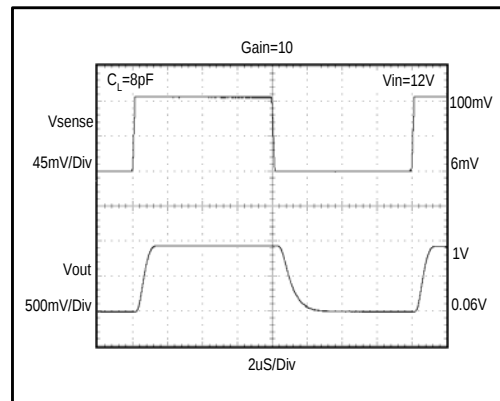


Fig 6. Large Signal Transient Response 10X

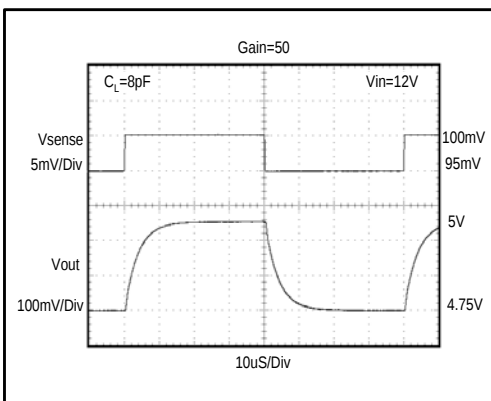


Fig 7. Small Signal Transient Response 50X

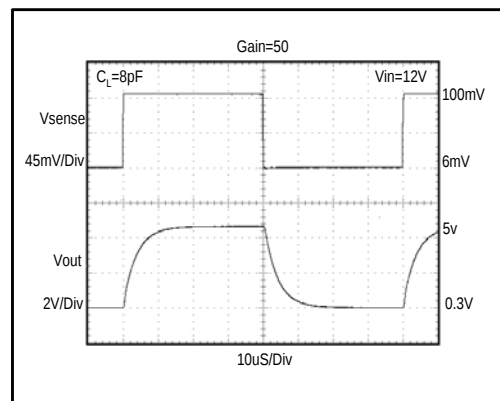
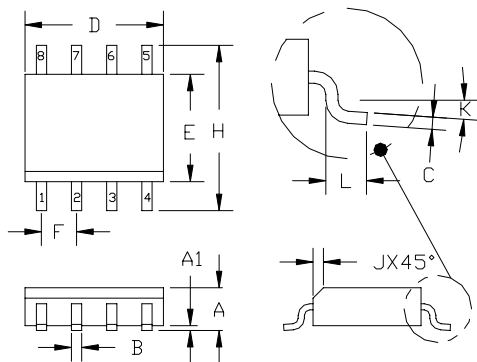


Fig 8. Large Signal Transient Response 50X

Package Outline

8-LEAD SOIC



3. MOLDED PACKAGE SHALL CONFORM TO JEDEC STANDARD CONFIGURATION MS-012 VARIATION AA.

② DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSIONS.

① CONTROLLING DIMENSIONS: MILLIMETERS.

NOTES: (UNLESS OTHERWISE SPECIFIED)

DIMENSIONS ①					
DIM.	INCH		MM.		NOTE
	MIN.	MAX.	MIN.	MAX.	
A	.0532	.0688	1.35	1.75	----
A1	.0040	.0098	.10	.25	----
B	.013	.020	.33	.51	----
C	.0075	.0098	.19	.25	----
D	.1890	.1968	4.80	5.00	②
E	.1497	.1574	3.80	4.00	②
F	.050	BSC	1.27	BSC	----
H	.2284	.2440	5.80	6.20	----
J	.0099	.0196	.25	.50	----
K	0°	8°	0°	8°	----
L	.016	.050	.40	1.27	----

IXYS Corporation makes no representations or warranties with respect to the accuracy or completeness of the contents of this publication and reserves the right to make changes to specifications and product descriptions at any time without notice. Neither circuit patent licenses nor indemnity are expressed or implied. Except as set forth in IXYS' Standard Terms and Conditions of Sale, IXYS Corporation assumes no liability whatsoever, and disclaims any expressed or implied warranty, relating to its products including, but not limited to, the implied warranty of merchantability, fitness for a particular purpose, or infringement of any intellectual property right.

Компания «Life Electronics» занимается поставками электронных компонентов импортного и отечественного производства от производителей и со складов крупных дистрибьюторов Европы, Америки и Азии.

С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибьюторских договоров

Мы предлагаем:

- Конкурентоспособные цены и скидки постоянным клиентам.
- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
- Работу по проектам и поставку образцов.
- Формирование склада под заказчика.
- Сертификаты соответствия на поставляемую продукцию (по желанию клиента).
- Тестирование поставляемой продукции.
- Поставку компонентов, требующих военную и космическую приемку.
- Входной контроль качества.
- Наличие сертификата ISO.

В составе нашей компании организован Конструкторский отдел, призванный помогать разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



Тел: +7 (812) 336 43 04 (многоканальный)

Email: org@lifeelectronics.ru

www.lifeelectronics.ru